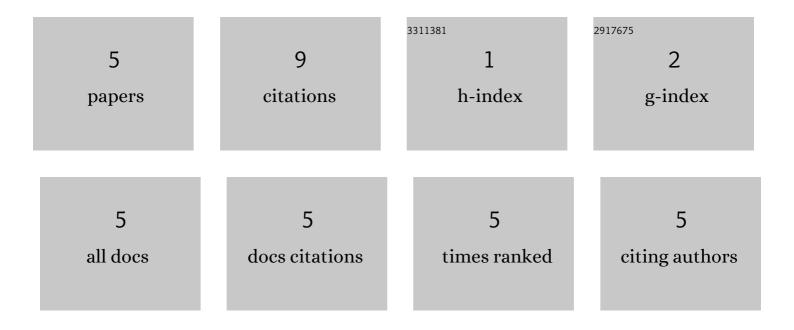
Qianshu Wu

List of Publications by Year in descending order

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ΟιλΝέμι Μ/Π

#	Article	IF	CITATIONS
1	Charge Control in Schottky-Type p-GaN Gate HEMTs With Partially and Fully Depleted p-GaN Conditions. IEEE Transactions on Electron Devices, 2022, 69, 2262-2269.	3.0	3
2	Mechanism of high conduction on the N polar face of GaN. Journal of Applied Physics, 2022, 131, 235701.	2.5	0
3	Numerical analysis of the GaN trench MIS barrier Schottky diodes with high dielectric reliability and surge current capability. AIP Advances, 2022, 12, .	1.3	1
4	Threshold Voltage Engineering in Al ₂ O ₃ /AlGaN/GaN MISHEMTs with Thin Barrier Layer: MIS-gate Charge Control and High Threshold Voltage Achievement. , 2021, , .		4
5	Influence of the Groove Depth on the Electrical Characteristics of the Vertical GaN Trench MOSFETs. , 2020, , .		1